

808nm Laser Diode

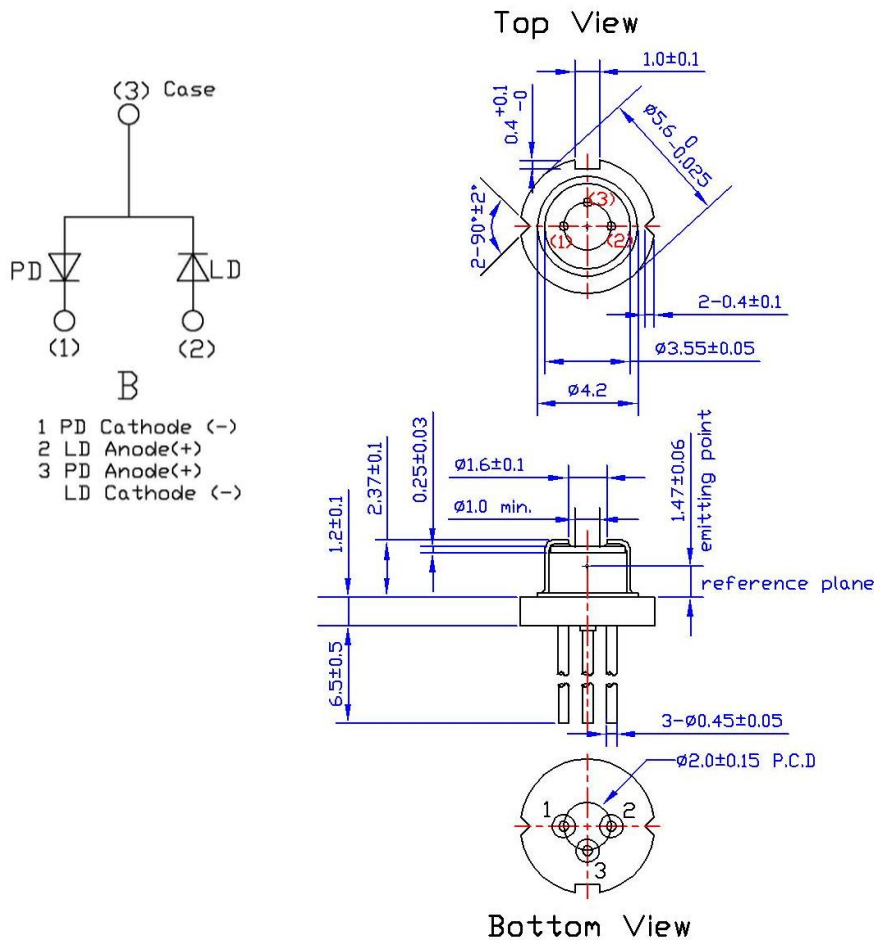
808nm Laser Diode

U-LD-80B051B

■ Specifications

- (1) Device: Laser Diode
 (2) Structure: TO-18 (ϕ 5.6mm), With Pb free glass cap, PD
 (3) Power Output: 200mW

■ External dimensions(Unit : mm)

■ Absolute Maximum Ratings($T_c=25^\circ\text{C}$)

Parameter	Symbols	Ratings	Units
Optical Output	Po	200	mW
Reverse Voltage	Laser	Vr	2
	PIN PD	Vr(PIN)	30
Operating Temperature (Case)	Top	-10~+50	$^\circ\text{C}$
Storage Temperature	Tstg	-10~+85	$^\circ\text{C}$

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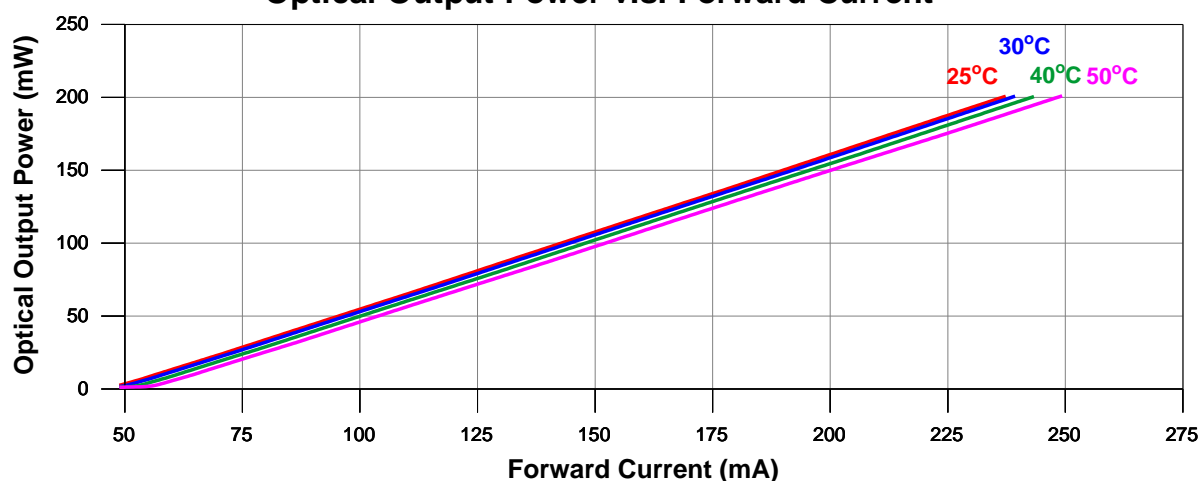
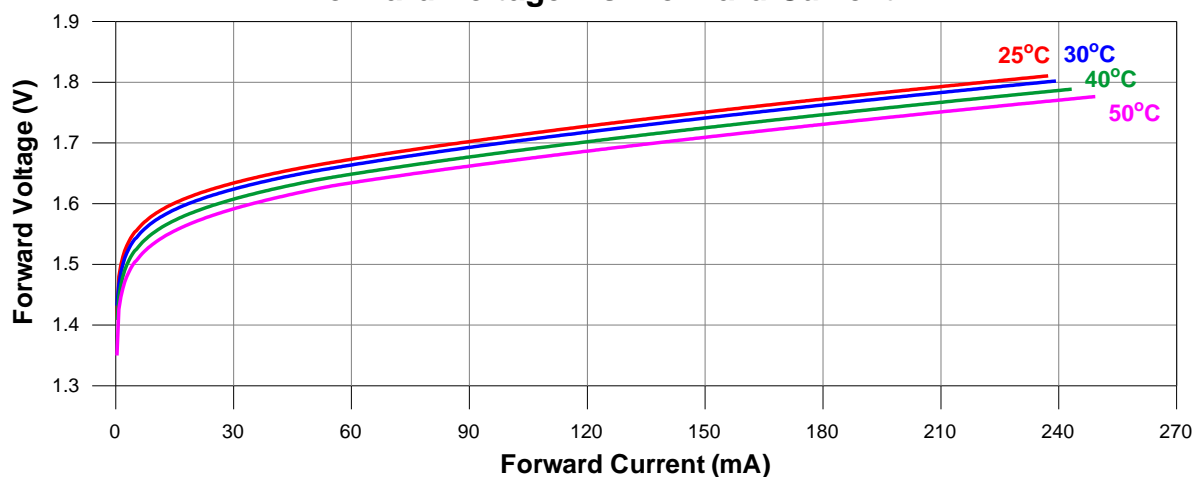
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Ver.1 2014/12

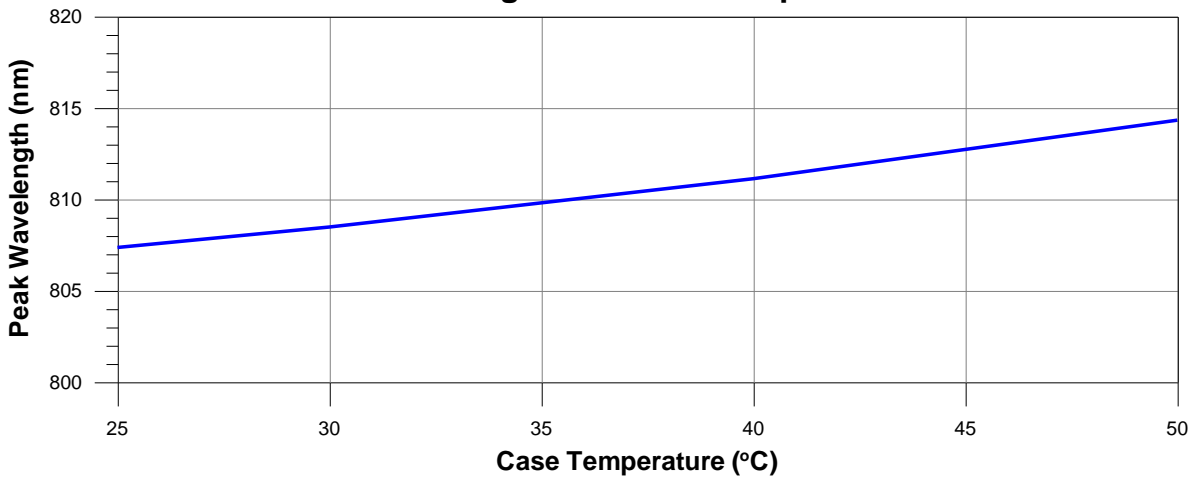
808nm Laser Diode**Electrical and Optical Characteristics(Tc=25°C)**

Parameter	Symbols	Conditions	Min.	Typ.	Max.	Units	
Threshold Current	I _{th}	-	-	50	70	mA	
Operating Current	I _{op}	P _o =200mW	-	235	265	mA	
Operating Voltage	V _{op}	-	-	1.8	1.95	Volts	
Slope Efficiency	η	150mW-50mW	0.8	1.09	-	mW/mA	
		I _{150mW} -I _{50mW}					
Monitor Current	I _m	P _o =200mW	-	0.35	2	mA	
Beam Divergence (FWHM)	Parallel	θ //	P _o =200mW	-	7.5	12	deg.
	Perpendicular	θ ⊥	P _o =200mW	-	30	40	deg.
Lasing Wavelength*	λ	P _o =200mW	805	808	811	nm	

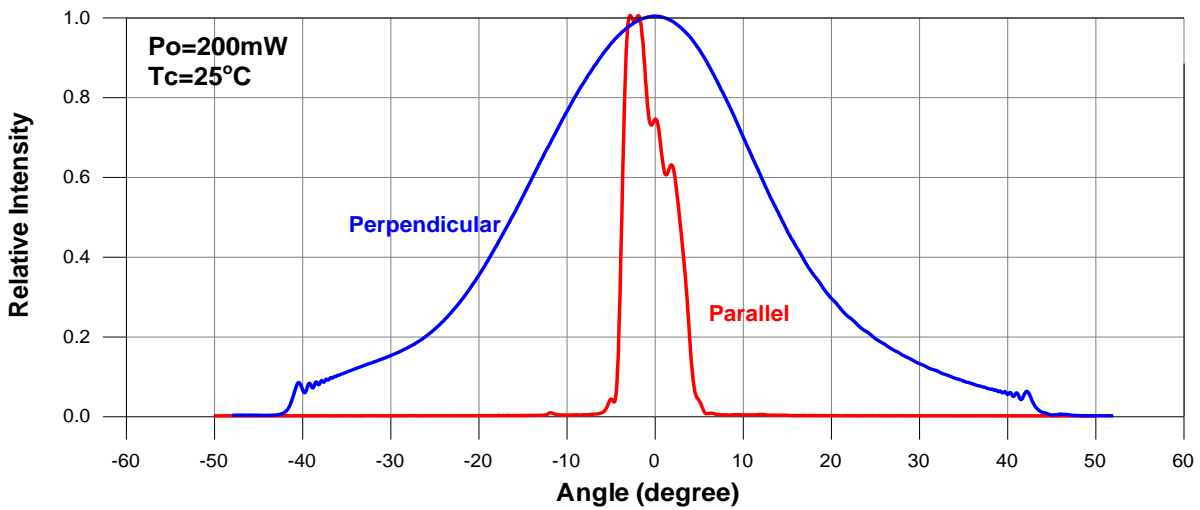
©θ // and θ ⊥ are defined as the angle within which the intensity is 50% of the peak value.

Typical characteristic curves**Optical Output Power v.s. Forward Current****Forward Voltage v.s. Forward Current**

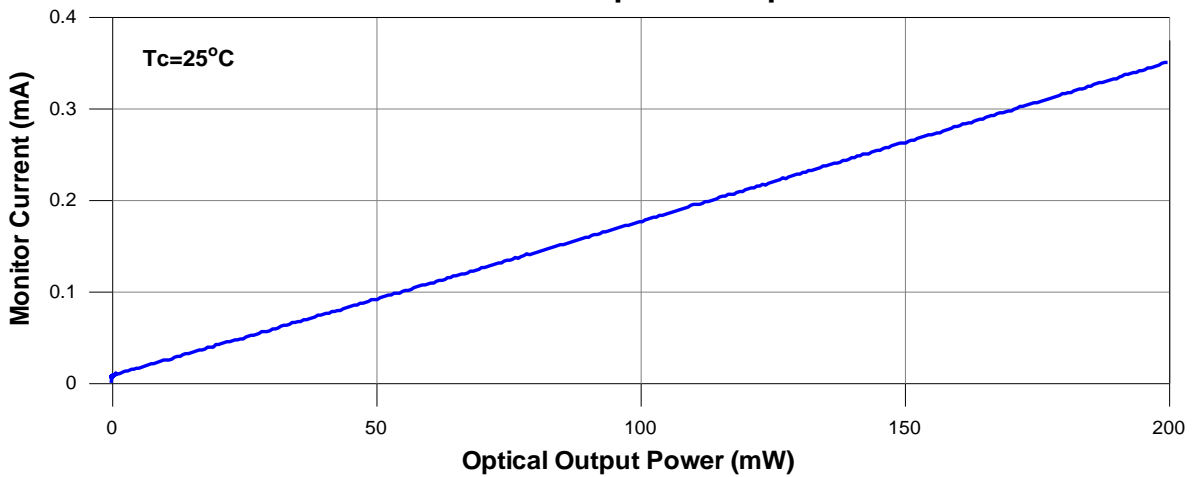
Peak Wavelength v.s. Case Temperature



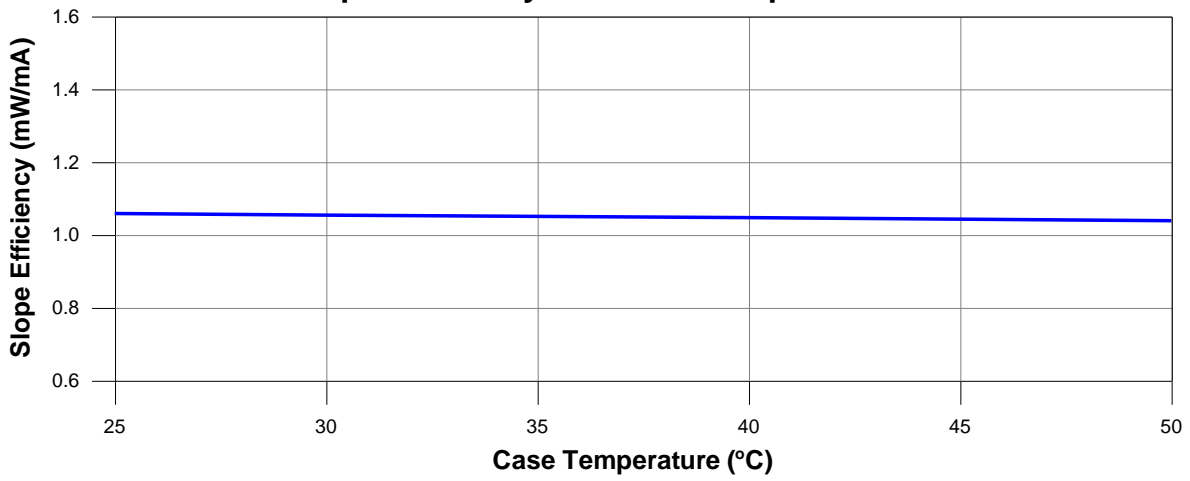
Far-Field Pattern



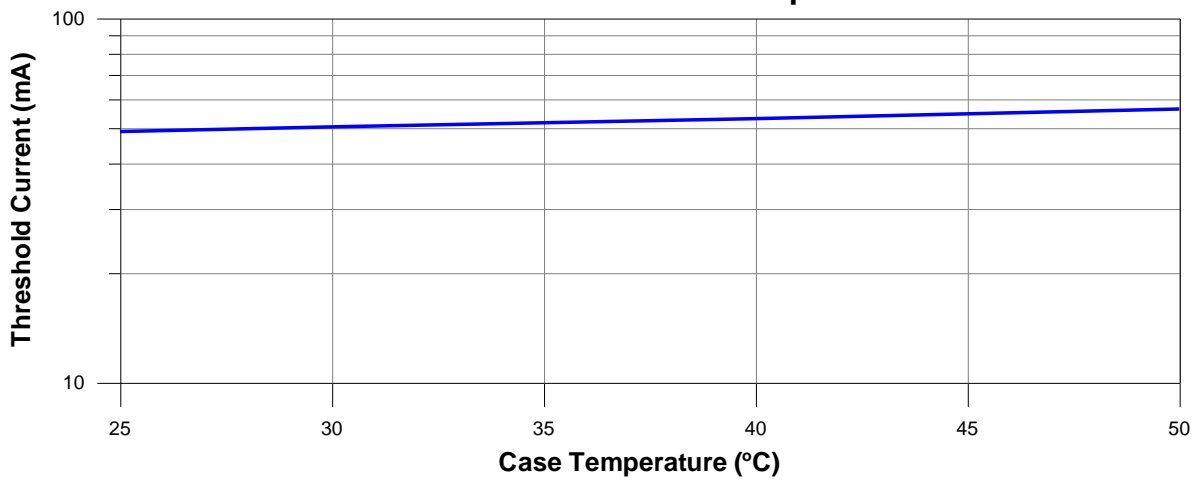
Monitor Current v.s. Optical Output Power



Slope Efficiency v.s. Case Temperature



Threshold Current v.s. Case Temperature



■ Precautions**QUALITY ASSURANCE**

After any processing of laser chip or laser diode TO-CAN (LD) by the customer, the performance, yield and reliability of the product, in which the chip or LD is applied, are subject to change due to customer's handling, assembly, testing, and processing. Because laser chip and LD are strongly affected by environmental conditions, physical stress, and chemical stresses imposed by customer that are not in Union Optronics Corp. (UOC) control and hence no guarantee on the characteristics and the reliability at all after the shipment. Also, UOC does not have any responsibility for field failures in a customer product. When attaching a heat sink to laser chip or LD, be careful not to apply excessive force to the device in the process.

SAFETY PRECAUTIONS

Although Union Optronics Corp. (UOC) keeps improving quality and reliability of its laser chip and laser diode TO-CAN (LD), semiconductor devices in general can malfunction or fail due to their intrinsic characteristics. Hence, it is required that the customer's products are designed with full regard to safety by incorporating the redundancy, fire prevention, error prevention so that any problems or error with UOC laser chip or LD does not cause any accidents resulting in injury, death, fire, property damage, economic damage, or environmental damage. In case customer wants to use UOC laser chip or LD in the systems requiring high safety, customer is requested to confirm safety of entire systems with customer's own testing.

SPECIFICATIONS ARE SUBJECT TO CHANGE WITHOUT NOTICE.

The information provided by Union Optronics Corp. (UOC), including but not limited to technical specifications, recommendations, and application notes relating to laser chip or laser diode TO-CAN (LD) is believed to be reliable and accurate and is subject to change without notice. UOC reserves the right to change its assembly, test, design, form, specification, control, or function without notice.